# Power MOSFET 4.4 Amps, 20 Volts

**P-Channel TSOP-6** 

#### Features

- Ultra Low R<sub>DS(on)</sub>
- Higher Efficiency Extending Battery Life
- Miniature TSOP-6 Surface Mount Package
- These Devices are Pb-Free and are RoHS Compliant
- NVGS Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable

#### Applications

• Power Management in Portable and Battery–Powered Products, i.e.: Cellular and Cordless Telephones, and PCMCIA Cards

#### **MAXIMUM RATINGS** (T<sub>J</sub> = $25^{\circ}$ C unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>	-20	Volts
Gate-to-Source Voltage - Continuous	V <sub>GS</sub>	±12	Volts
$\begin{array}{l} \mbox{Thermal Resistance} \\ \mbox{Junction-to-Ambient (Note 1)} \\ \mbox{Total Power Dissipation @ T_A = 25^{\circ}C} \\ \mbox{Drain Current - Continuous @ T_A = 25^{\circ}C} \\ \mbox{- Pulsed Drain Current (T_p < 10  \mu S)} \end{array}$	R <sub>θJA</sub> P <sub>d</sub> I <sub>D</sub> I <sub>DM</sub>	244 0.5 -2.2 -10	°C/W Watts Amps Amps
$\begin{array}{l} \mbox{Thermal Resistance} \\ \mbox{Junction-to-Ambient (Note 2)} \\ \mbox{Total Power Dissipation @ T_A = 25^{\circ}C} \\ \mbox{Drain Current - Continuous @ T_A = 25^{\circ}C} \\ \mbox{- Pulsed Drain Current (T_p < 10 \ \mu S)} \end{array}$	R <sub>θJA</sub> P <sub>d</sub> I <sub>D</sub> I <sub>DM</sub>	128 1.0 –3.1 –14	°C/W Watts Amps Amps
$\begin{array}{l} \mbox{Thermal Resistance} \\ \mbox{Junction-to-Ambient (Note 3)} \\ \mbox{Total Power Dissipation @ T_A = 25^{\circ}C} \\ \mbox{Drain Current - Continuous @ T_A = 25^{\circ}C} \\ \mbox{- Pulsed Drain Current (T_p < 10 \ \mu S)} \end{array}$	R <sub>θJA</sub> P <sub>d</sub> I <sub>D</sub> I <sub>DM</sub>	62.5 2.0 -4.4 -20	°C/W Watts Amps Amps
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	–55 to 150	°C
Maximum Lead Temperature for Soldering Purposes for 10 Seconds	ΤL	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

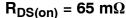
- 1. Minimum FR-4 or G-10 PCB, operating to steady state.
- Mounted onto a 2 in square FR-4 board (1 in sq, 2 oz. Cu. 0.06" thick single sided), operating to steady state.
- Mounted onto a 2 in square FR-4 board (1 in sq, 2 oz. Cu. 0.06" thick single sided), t < 5.0 seconds.</li>

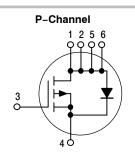


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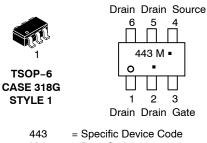
http://onsemi.com

4.4 AMPERES 20 VOLTS





#### MARKING DIAGRAM & PIN ASSIGNMENT



M = Date Code\*

= Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NTGS3443T1G	TSOP-6 (Pb-Free)	3000 / Tape & Reel
NVGS3443T1G	TSOP-6 (Pb-Free)	3000 / Tape & Reel

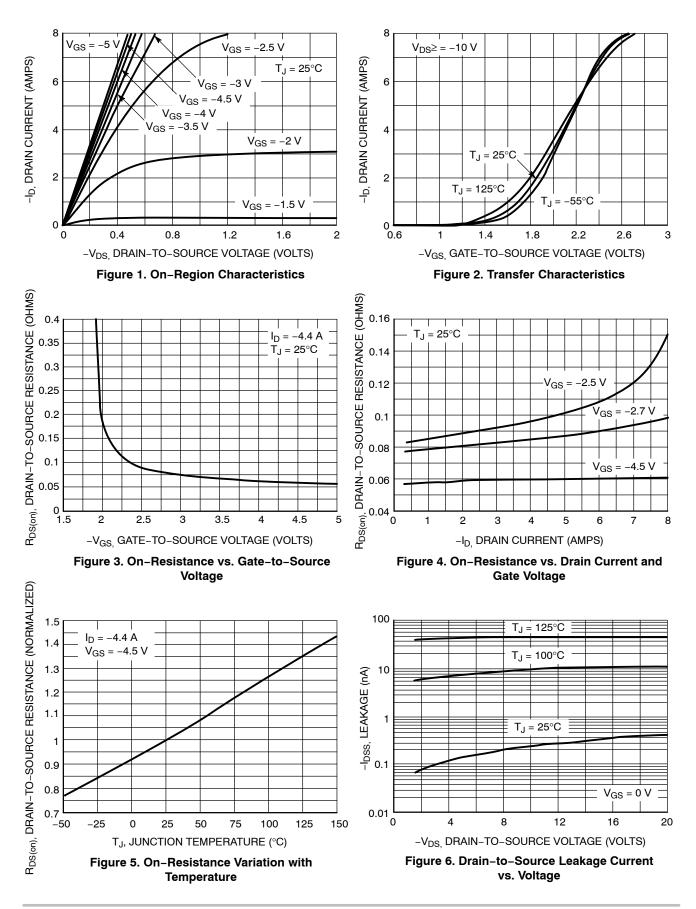
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted) (Notes 4 & 5)

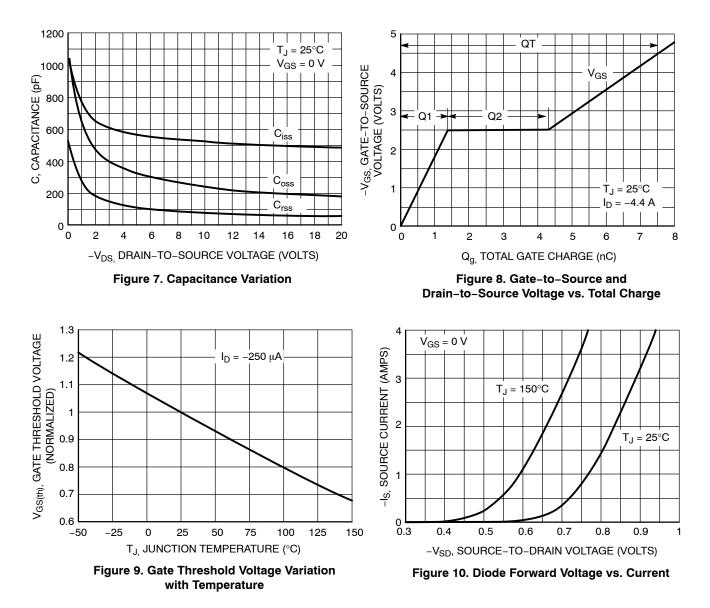
Characteristic			Min	Тур	Max	Unit
OFF CHARACTERISTICS		•	•	•	•	•
Drain–Source Breakdown Voltage ( $V_{GS}$ = 0 Vdc, I <sub>D</sub> = -10 $\mu$ A)			-20	-	_	Vdc
Zero Gate Voltage Drain Current ( $V_{GS} = 0 \text{ Vdc}, V_{DS} = -20 \text{ Vdc}, T_J = 25^{\circ}\text{C}$ ) ( $V_{GS} = 0 \text{ Vdc}, V_{DS} = -20 \text{ Vdc}, T_J = 70^{\circ}\text{C}$ )		I <sub>DSS</sub>			-1.0 -5.0	μAdc
$\label{eq:Gate-Body Leakage Current} \begin{aligned} & \text{Gate-Body Leakage Current} \\ & (\text{V}_{GS} = -12 \text{ Vdc}, \text{ V}_{DS} = 0 \text{ Vdc}) \end{aligned}$	I <sub>GSS</sub>	-	-	-100	nAdc	
Gate-Body Leakage Current (V <sub>GS</sub> = +12 Vdc, V <sub>DS</sub> = 0 Vdc)	I <sub>GSS</sub>	_	-	100	nAdc	
ON CHARACTERISTICS				•		•
Gate Threshold Voltage $(V_{DS} = V_{GS}, I_D = -250 \ \mu Adc)$		V <sub>GS(th)</sub>	-0.60	-0.95	-1.50	Vdc
$\begin{array}{l} \mbox{Static Drain-Source On-State Re} \\ (V_{GS} = -4.5 \mbox{ Vdc}, \mbox{ I}_{D} = -4.4 \mbox{ Add} \\ (V_{GS} = -2.7 \mbox{ Vdc}, \mbox{ I}_{D} = -3.7 \mbox{ Add} \\ (V_{GS} = -2.5 \mbox{ Vdc}, \mbox{ I}_{D} = -3.5 \mbox{ Add} \\ \end{array}$	2) 2)	R <sub>DS(on)</sub>		0.058 0.082 0.092	0.065 0.090 0.100	Ω
Forward Transconductance $(V_{DS} = -10 \text{ Vdc}, I_D = -4.4 \text{ Adc})$		9FS	-	8.8	_	mhos
DYNAMIC CHARACTERISTICS		÷				
Input Capacitance	(V <sub>DS</sub> = -5.0 Vdc, V <sub>GS</sub> = 0 Vdc, f = 1.0 MHz)	C <sub>iss</sub>	-	565	-	pF
Output Capacitance		C <sub>oss</sub>	-	320	-	pF
Reverse Transfer Capacitance	,	C <sub>rss</sub>	-	120	-	pF
SWITCHING CHARACTERISTIC	5		-			
Turn-On Delay Time		t <sub>d(on)</sub>	-	10	25	ns
Rise Time	$      (V_{DD} = -20 \; Vdc, \; I_D = -1.0 \; Adc, \\ V_{GS} = -4.5 \; Vdc, \; R_g = 6.0 \; \Omega ) $	tr	-	18	45	ns
Turn-Off Delay Time		t <sub>d(off)</sub>	-	30	50	ns
Fall Time		t <sub>f</sub>	-	31	50	ns
Total Gate Charge		Q <sub>tot</sub>	-	7.5	15	nC
Gate-Source Charge	(V <sub>DS</sub> = -10 Vdc, V <sub>GS</sub> = -4.5 Vdc, I <sub>D</sub> = -4.4 Adc)	Q <sub>gs</sub>	-	1.4	-	nC
Gate-Drain Charge		Q <sub>gd</sub>	-	2.9	-	nC
BODY-DRAIN DIODE RATINGS						
Diode Forward On-Voltage	$(I_{\rm S} = -1.7 \; {\rm Adc},  {\rm V}_{\rm GS} = 0 \; {\rm Vdc})$	V <sub>SD</sub>	-	-0.83	-1.2	Vdc
Reverse Recovery Time	(I <sub>S</sub> = -1.7 Adc, dI <sub>S</sub> /dt = 100 A/µs)	t <sub>rr</sub>	-	30	-	ns

Indicates Pulse Test: P.W. = 300 μsec max, Duty Cycle = 2%.
Handling precautions to protect against electrostatic discharge are mandatory.

#### **TYPICAL ELECTRICAL CHARACTERISTICS**



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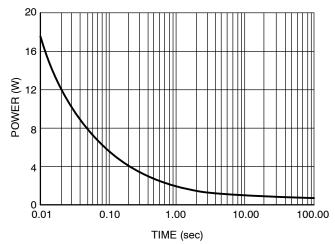


Figure 11. Single Pulse Power

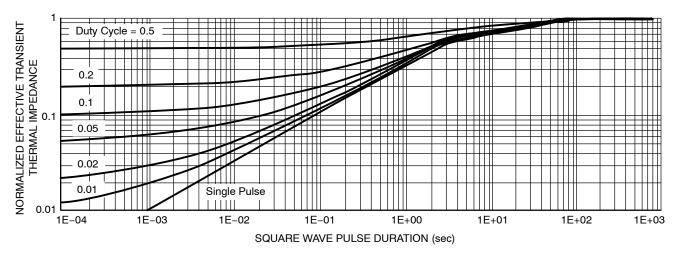


Figure 12. Normalized Thermal Transient Impedance, Junction-to-Ambient





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